

INFRARED EMITTING DIODE

Part Number: KM2520F3C03

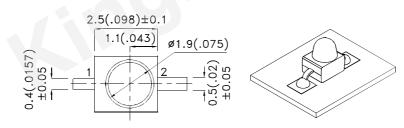
Features

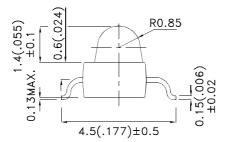
- Subminiature package.
- Mechanically and spectrally matched to the phototransistor.
- Gull wing lead.
- Long life solid state reliability.
- Low package profile.
- Package: 1000pcs / reel.
- Moisture sensitivity level : level 3.
- RoHS compliant.

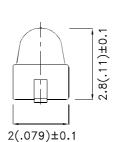
Description

F3 Made with Gallium Arsenide Infrared Emitting diodes.

Package Dimensions







- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.25(0.01") unless otherwise noted.
- Lead spacing is measured where the leads emerge from the package.
 The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
 The device has a single mounting surface. The device must be mounted according to the specifications.

DATE: APR/13/2013 PAGE: 1 OF 5 **SPEC NO: DSAA5108 REV NO: V.13A APPROVED: WYNEC CHECKED: Allen Liu** DRAWN: F.Cui ERP: 1202000467

Selection Guide

Part No.	Dice	Lens Type	Po (mW/sr) [2] @ 20mA		Po (mW/sr) [2] @ 50mA		Viewing Angle [1]
			Min.	Тур.	Min.	Тур.	201/2
KM2520F3C03	F3 (GaAs)	Water Clear	5	10	10	20	- 20°
			*3	*8	*8	*16	

Notes:

- 1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value. 2. Radiant Intensity/ luminous flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Parameter	P/N	Symbol	Тур.	Max.	Units	Test Conditions	
Forward Voltage [1]	F3	VF	1.2	1.6	V	IF=20mA	
Reverse Current	F3	lr		10	uA	V _R = 5V	
Capacitance	F3	С	90		pF	VF=0V;f=1MHz	
Peak Spectral Wavelength	F3	λP	940		nm	IF=20mA	
Spectral Bandwidth	F3	Δλ1/2	50		nm	IF=20mA	

Notes:

1. Forward Voltage: +/-0.1V.

2. Wavelength value is traceable to the CIE127-2007 compliant national standards.

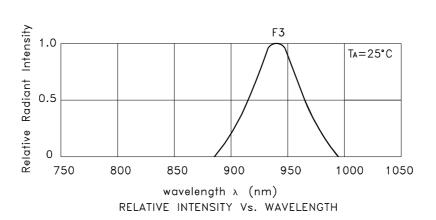
Absolute Maximum Ratings at TA=25°C

Abbolato maximum ratingo at 171 20 0						
Symbol	F3	Units mW				
PD	80					
lF	50	mA				
iFS	1.2	Α				
VR	5	V				
Та	-40 To +85	°C				
Тѕтс	-40 To +85	°C				
	Symbol PD IF iFS VR TA	Symbol F3 PD 80 IF 50 iFS 1.2 VR 5 TA -40 To +85				

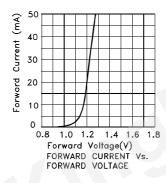
Note: 1. 1/100 Duty Cycle, 10µs Pulse Width.

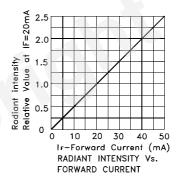
REV NO: V.13A DATE: APR/13/2013 PAGE: 2 OF 5 **SPEC NO: DSAA5108** APPROVED: WYNEC **CHECKED: Allen Liu** DRAWN: F.Cui ERP: 1202000467

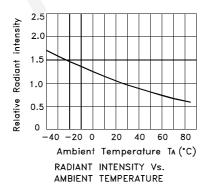
^{*} Radiant intensity value is traceable to the CIE127-2007 compliant national standards.

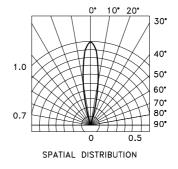


KM2520F3C03









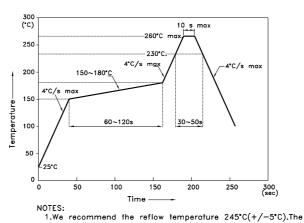
 SPEC NO: DSAA5108
 REV NO: V.13A
 DATE: APR/13/2013
 PAGE: 3 OF 5

 APPROVED: WYNEC
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KM2520F3C03

Reflow soldering is recommended and the soldering profile is shown below. Other soldering methods are not recommended as they might cause damage to the product.

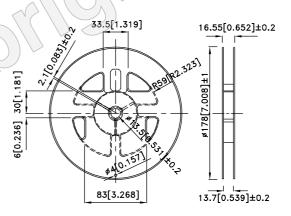
Reflow Soldering Profile For Lead-free SMT Process.



- 1.We recommend the reflow temperature 245°C(+/-5°C).The maximum soldering temperature should be limited to 260°C. 2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
- 3. Number of reflow process shall be 2 times or less.

Recommended Soldering Pattern (Units: mm; Tolerance: ± 0.1)

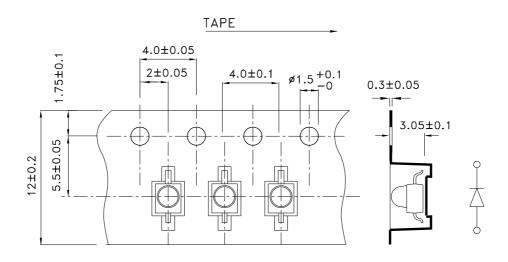
Reel Dimension



PAGE: 4 OF 5

ERP: 1202000467

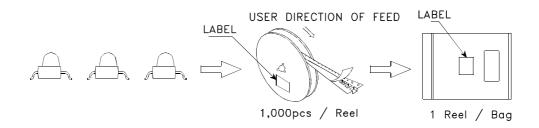
Tape Specifications (Units: mm)

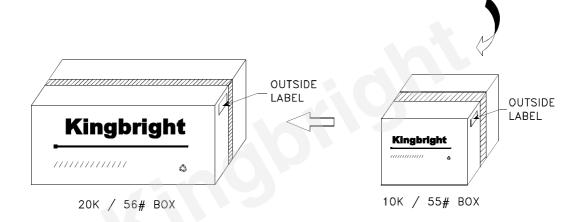


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PACKING & LABEL SPECIFICATIONS

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Detailed application notes are listed on our website. http://www.kingbright.com/application notes

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